

January 2001 Revised August 2001

74LCX32373

Low Voltage 32-Bit Transparent Latch with 5V Tolerant Inputs and Outputs (Preliminary)

General Description

The LCX32373 contains thirty-two non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{\text{OE}}$) is LOW. When $\overline{\text{OE}}$ is HIGH, the outputs are in a high impedance state.

The LCX32373 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment

The LCX32373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- \blacksquare 2.3V–3.6V $\rm V_{CC}$ specifications provided
- 5.4 ns t_{PD} max (V_{CC} = 3.3V), 20 μ A I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- \blacksquare ±24 mA output drive (V_{CC} = 3.0V)
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V
- Packaged in plastic Fine-Pitch Ball Grid Array (FBGA) (Preliminary)

Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX32373GX	BGA96A	96-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
(Note 2)	(Preliminary)	[TAPE and REEL]
Note 2: BGA package	available in Tape and Rec	only.
Logic Sym	bol	
	l ₀ l ₁ l ₂ l ₃ l ₄ l ₅ l ₆	17 18 19 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28 29 30 31
_	○ □ 1	<u>○E</u> ₃ ○ —
_	O OE₂	<u> </u>
_	LE ₁	LE ₃ ——
_	LE ₂	LE ₄
	O ₀ O ₁ O ₂ O ₃ O ₄ O ₅ O ₆	$O_7 \ O_8 \ O_9 \ O_{10} O_{11} O_{12} O_{13} O_{14} O_{15} O_{16} O_{17} O_{18} O_{19} O_{20} O_{21} O_{22} O_{23} O_{24} O_{25} O_{26} O_{27} O_{28} O_{29} O_{30} O_{31}$

Connection Diagram

	1	2	3	4	5	6
⋖	0	0	0	0	0	0
В	Ó	0	O	O	0	0
ပ	0	0	0	0	0	0
۵	O	0	0	0	0	0
ш	0	0	0	0	0	0
ш	0	0	0	0	0	0
മ	0	0	0	0	0	0
I	0	0	0	0	0	0
っ	0	0	0	0	0	0
ᅩ	0	0	0	0	0	0
_	0	0	0	0	0	0
Σ	0	0	0	0	0	0
z	0	0	0	0	0	0
۵	0	0	0	0	0	0
Œ	0	0	0	0	0	0
⊢	0	0	0	0	0	0

(Top Thru View)

Pin Descriptions

Pin Names	Description
ŌĒn	Output Enable Input (Active LOW)
LE _n	Latch Enable Input
I ₀ - I ₃₁	Inputs
O ₀ - O ₃₁	Outputs

FBGA Pin Assignments

		1	2	3	4	5	6
Α		O ₁	O ₀	ŌE ₁	LE ₁	I ₀	I ₁
В		O ₃	O ₂	GND	GND	l ₂	l ₃
С		O ₅	O ₄	V _{CC}	V _{CC}	I ₄	I ₅
D		07	O ₆	GND	GND	I ₆	I ₇
Е		O ₉	O ₈	GND	GND	I ₈	l ₉
F		O ₁₁	O ₁₀	Vcc	V _{CC}	I ₁₀	I ₁₁
G		O ₁₃	O ₁₂	GND	GND	I ₁₂	I ₁₃
Н		O ₁₄	O ₁₅	OE ₂	LE ₂	I ₁₅	I ₁₄
J		O ₁₇	O ₁₆	OE ₃	LE ₃	I ₁₆	I ₁₇
K	X	O ₁₉	O ₁₈	GND	GND	I ₁₈	I ₁₉
L	Mills	O ₂₁	O ₂₀	Vcc	V _{CC}	I ₂₀	l ₂₁
M		O ₂₃	022	GND	GND	l ₂₂	l ₂₃
N	U	O ₂₅	O ₂₄	GND	GND	l ₂₄	l ₂₅
P		O ₂₇	O ₂₆	V _{CC}	V _{CC}	I ₂₆	l ₂₇
R		O ₂₉	O ₂₈	GND	GND	I ₂₈	l ₂₉
Т		O ₃₀	O ₃₁	ŌE ₄	LE ₄	I ₃₁	I ₃₀

Truth Table

	Inputs		Outputs
LE _n	OEn	I _n	O _n
Х	Н	Х	Z
Н	L	L	L
Н	L	Н	Н
L	L	Χ	O ₀

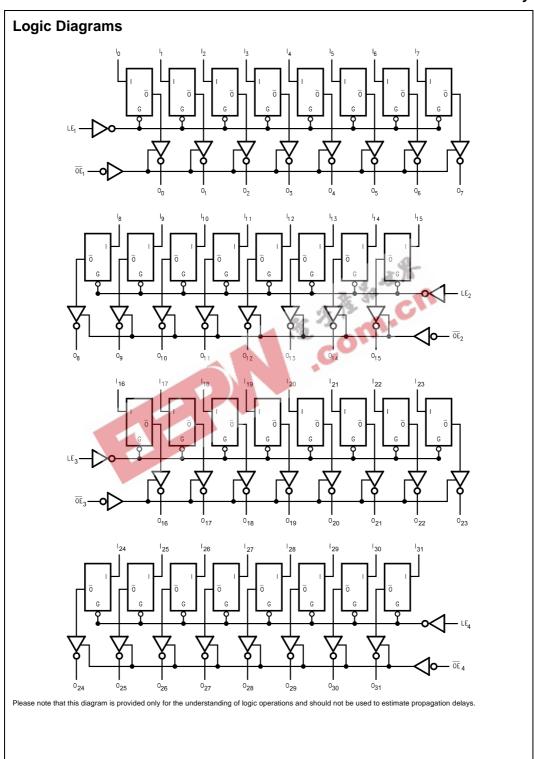
- H = HIGH Voltage Level
- L = LOW Voltage Level X = Immaterial

- Z = High Impedance $O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable$

Functional Description

The LCX32373 contains thirty-two D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 32-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the $I_{\rm n}$ enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time

its I input changes. When $\ensuremath{\mathsf{LE}}_n$ is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW, the standard outputs are in the 2-state mode. When $\overline{\text{OE}}_{\text{n}}$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.



Symbol	Parameter	Value	Conditions	Units	
√cc	Supply Voltage	-0.5 to +7.0		V	
/ _I	DC Input Voltage	-0.5 to +7.0		V	
/ ₀	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V	
		-0.5 to $V_{CC} + 0.5$	Output in HIGH or LOW State (Note 4)	l v	
IK	DC Input Diode Current	-50	V _I < GND	mA	
OK	DC Output Diode Current	-50	V _O < GND	mA	
		+50	V _O > V _{CC}	IIIA	
0	DC Output Source/Sink Current	±50		mA	
СС	DC Supply Current per Supply Pin	±100		mA	
GND	DC Ground Current per Ground Pin	±100		mA	
$\Gamma_{\rm STG}$	Storage Temperature	-65 to +150		°C	

Recommended Operating Conditions (Note 5)

Symbol	Parameter	Min	Max	Units
V _{CC}	Supply Voltage	Operating 2.0	3.6	V
	Da	ta Retention 1.5	3.6	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage HIGH o	r LOW State 0	V _{CC}	V
		3-STATE 0	5.5	V
I _{OH} /I _{OL}		3.0V - 3.6V	±24	
	V _{CC} =	2.7V – 3.0V	±12	mA
	V _{CC} =	2.3V – 2.7V	±8	
T _A	Free-Air Operating Temperature	-40	85	°C
Δt/ΔV	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: Io Absolute Maximum Rating must be observed.

Note 5: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
-	Farameter	Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.3 – 3.6	V _{CC} - 0.2		
		$I_{OH} = 8 \text{ mA}$	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
V _{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu\text{A}$	2.3 – 3.6		0.2	
		$I_{OL} = 8 \text{ mA}$	2.3		0.6	٧
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	
		$I_{OL} = 16 \text{ mA}$	3.0		0.4	
		$I_{OL} = 24 \text{ mA}$	3.0		0.55	
I _I	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 – 3.6		±5.0	μΑ
loz	3-STATE Output Leakage	$0 \le V_O \le 5.5V$	2.3 – 3.6		±5.0	
		$V_I = V_{IH}$ or V_{IL}	2.3 - 3.0		±5.0	μA
l _{OFF}	Power-Off Leakage Current	V_1 or $V_0 = 5.5V$	0	i i	10	μΑ

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	v _{cc}	T _A = -40°0	C to +85°C	Units
Cymbol	i didilictor	Conditions	(V)	Min	Max	Omio
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	μА
		3.6V ≤ V _I , V _O ≤ 5.5V (Note 6)	2.3 – 3.6		±20	μΛ
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μΑ

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

			$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $R_L = 500\Omega$					
	Paramatar	$V_{CC} = 3.3V \pm 0.3V$		V _{CC} = 2.7V		$\rm V_{CC}=2.5V\pm0.2V$		Units
Symbol	Parameter	C _L =	C _L = 50 pF		C _L = 50 pF		C _L = 30 pF	
		Min	Max	Min	Max	Min	Max	
t _{PHL}	Propagation Delay	1.5	5.4	1.5	5.9	1.5	6.5	20
t _{PLH}	I _n to O _n	1.5	5.4	1.5	5.9	1.5	6.5	ns
t _{PHL}	Propagation Delay	1.5	5.5	1.5	6.4	1.5	6.6	20
t _{PLH}	LE to O _n	1.5	5.5	1.5	6.4	1.5	6.6	ns
t _{PZL}	Output Enable Time	1.5	6.1	1.5	6.5	1.5	7.9	
t_{PZH}		1.5	6.1	1.5	6.5	1.5	7.9	ns
t _{PLZ}	Output Disable Time	1.5	6.0	1.5	6.3	1.5	7.2	20
t_{PHZ}		1.5	6.0	1.5	6.3	1.5	7.2	ns
t _S	Setup Time, In to LE	2.5	13	2.5	117	3.0		ns
t _H	Hold Time, In to LE	1.5		1.5	,	2.0		ns
t _W	LE Pulse Width	3.0		3.0	_	3.5		ns

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$	Units
Symbol	i di diffeter	Conditions	(V)	Typical	Onits
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	0.6	V
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
1		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	-0.6	V

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	V_{CC} = Open, V_I = 0V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_{I} = 0V$ or V_{CC} , $f = 10$ MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

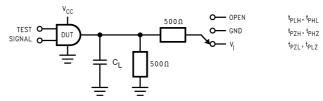
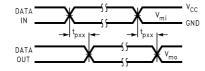
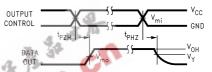


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

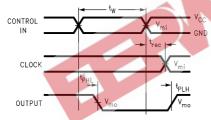
Test	Switch	
t _{PLH} , t _{PHL}	Open	
t _{PZL} , t _{PLZ}	6V at V_{CC} = 3.3 \pm 0.3V, and 2.7V V_{CC} x 2 at V_{CC} = 2.5 \pm 0.2V	
t _{PZH} , t _{PHZ}	GND	



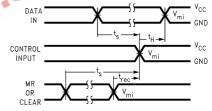
Waveform for Inverting and Non-Inverting Functions



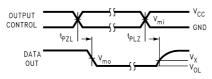
3-STATE Output High Enable and Disable Times for Logic



Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

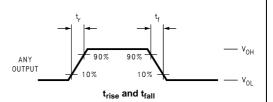
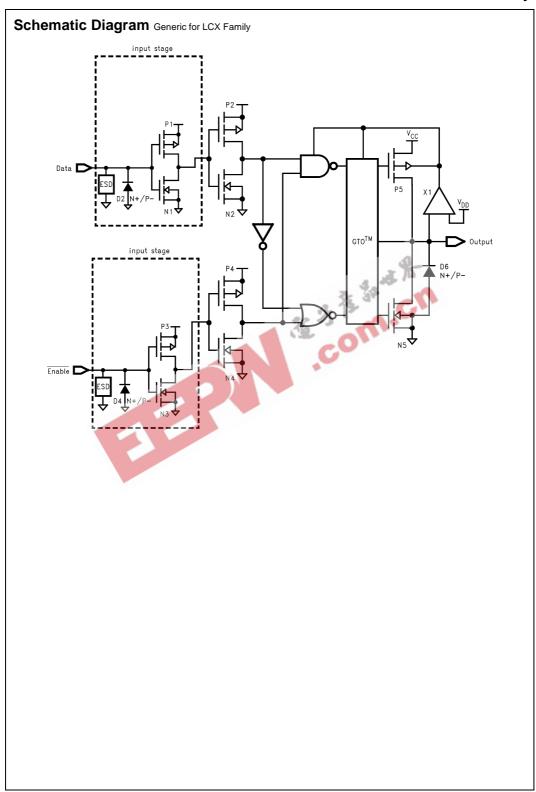
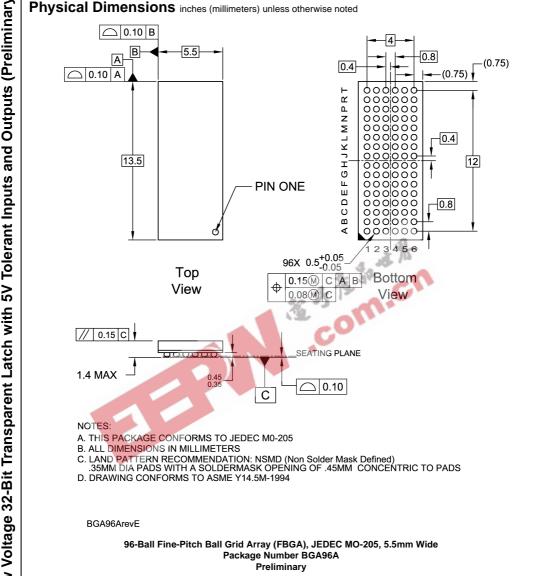


FIGURE 2. Waveforms (Input Characteristics; f = 1MHz, $t_r = t_f = 3ns$)

Symbol	V _{CC}			
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V	
V_{mi}	1.5V	1.5V	V _{CC} /2	
V _{mo}	1.5V	1.5V	V _{CC} /2	
V _x	V _{OL} + 0.3V	V _{OL} + 0.3V	V _{OL} + 0.15V	
V_{y}	V _{OH} – 0.3V	V _{OH} – 0.3V	V _{OH} – 0.15V	





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